Docket No. 90066.000371/IZ-200301001

Declaration and Power of Attorney For Patent Application

English Language Declaration

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name,

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

SEMICONDUCTOR PAC		ITIED HIGH VOLTAGE APPLICATIONS	
the specification of which	:h		
(check one)			
x is attached hereto.			
uas filed on		as United States Application No	. or PCT International
Application Number			
and was amended o	on		
		(if applicable)	
I hereby state that I havincluding the claims, as	e reviewed and under amended by any am	erstand the contents of the above endment referred to above.	identified specification,
1.56, including for cor	ntinuation-in-part app of the prior application	on which is material to patentability dications, material information when and the national or PCT interna	ich became available
application(s) for paten application which design below and have also	t, or plant breeder's nated at least one identified below, by der's rights certificate	er 35 U.S.C. 119(a)-(d) or (f), or rights certificate(s), or 365(a) of country other than the United Stachecking the box, any foreign acts, or any PCT international appropriority is claimed.	any PCT International ates of America, listed application for patent.
Prior Foreign Application	n(s)		Priority Not Claimed
2003-4025	Korea	21 January 2003	
(Number)	(Country)	(Day/Month/Year Filed)	
(Number)	(Country)	(Day/Month West File 4)	
		(Day/Month/Year Filed)	
(Number)	(Country)	(Day/Month/Year Filed)	_

None		
(Application Serial No.)	(Filing Date)	
(Application Serial No.)	(Filing Date)	
(Application Serial No.)	(Filing Date)	
ection 365(c) of any PCT Interna sofar as the subject matter of e nited States or PCT Internationa .S.C. Section 112, I acknowledg	ational application designating each of the claims of this app al application in the manner p ge the duty to disclose to the	any United States application(s), the United States, listed below an olication is not disclosed in the provided by the first paragraph of United States Patent and Tradema
ection 365(c) of any PCT Internation sofar as the subject matter of enited States or PCT International S.C. Section 112, I acknowledge ffice all information known to mection 1.56 which became availate PCT International filing date of the sofar and section 1.56.	ational application designating each of the claims of this application in the manner part the duty to disclose to the late to be material to patentab ble between the filing date of	the United States, listed below an plication is not disclosed in the proposition of provided by the first paragraph of
ection 365(c) of any PCT Internations as the subject matter of ented States or PCT International S.C. Section 112, I acknowled of the fice all information known to mection 1.56 which became availa	ational application designating each of the claims of this application in the manner part the duty to disclose to the late to be material to patentab ble between the filing date of	the United States, listed below an plication is not disclosed in the properties of provided by the first paragraph of United States Patent and Tradema lility as defined in Title 37. C. F.
ection 365(c) of any PCT Internations sofar as the subject matter of enited States or PCT International S.C. Section 112, I acknowledge ffice all information known to mection 1.56 which became availate PCT International filing date of the None	ational application designating each of the claims of this application in the manner part to be material to patentable between the filing date of his application:	the United States, listed below as plication is not disclosed in the provided by the first paragraph of United States Patent and Trademaility as defined in Title 37, C. F. the prior application and the nation (Status)

fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

POWER OF ATTORNEY: As a named inventor, I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith. (list name and registration number)

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Citizenship Republic of Korea	

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